N on-adiabatic electron pumping: maxim al current with m inim al noise

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The noise properties of pump currents through an open double quantum dot setup with nonadiabatic ac driving are investigated. D riving frequencies close to the internal resonances of the double dot-system m ark the optim al working points at which the pump current assumes a m axim um while its noise power possesses a rem arkably low m inim um. A rotating-wave approximation provides analytical expressions for the current and its noise power and allows to optim ize the noise characteristics. The analytical results are compared to numerical results from a F loquet transport theory.

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In m esoscopic conductors, a cyclic adiabatic change of the parameters can induce a pump current, i.e., a nonvanishing dc current owing even in the absence of any external bias voltage [1, 2, 3]. For adiabatic quantum pumps [4, 5, 6, 7, 8], the transferred charge per cycle is determined by the area enclosed in parameter space during the cyclic evolution [4, 5]. This implies that the resulting current is proportional to the driving frequency and, thus, suggests that non-adiabatic electron pum ping is more e ective. For practical applications, it is also desirable to operate the quantum pump in a low-noise regime. It has been found that adiabatic pumps can be practically noiseless [9]. This happens, however, on the expense of acquiring a small or even vanishing current [10]. Therefore, the question arises whether it is possible to boost the pump current by increasing the driving frequency while keeping the noise level very low.

N on-adiabatic electron pumping can be achieved experimentally with double quantum dots under the in uence of microwave radiation [11, 12, 13, 14]. In this letter we study the transport properties in this non-adiabatic regime. Our main aim is to ndideal parameter regimes in which a large pump current is associated with low current noise. For the optimization of the system parameters, it is bene cial to obtain, besides a numerical solution, also analytic expressions for the transport quanti ers. Therefore, within a rotating-wave approximation (RW A), we map the driven transport problem to a static one which we solve analytically. In doing so, a particular challenge represents the consistent RW A treatment of the connecting leads in the presence of acelds.

The double-dot model. We consider the setup sketched in Fig. 1 described by the time-dependent H am iltonian H (t) = $H_{dots}(t) + H_{leads} + H_{contacts}$, where the di erent contributions correspond to the quantum dots, the leads, and the tunneling coupling to the respective lead. We disregard interaction and spin e ects and assume that intra-dot excitations do not play a role such that each dot is well described by a single energy level.

Then, the double quantum dot Ham iltonian reads

$$H_{dots}(t) = \frac{1}{2} (c_1^{y} c_2 + c_2^{y} c_1) + \frac{(t)}{2} (c_1^{y} c_1 - c_2^{y} c_2); \quad (1)$$

where the ferm ion operators $c_{1,2}$ and $c_{1,2}^y$ annihilate and create an electron in the left and the right dot, respectively. The on-site energy di erence $(t) = _0 + A \cos(t)$ is determined by the static internal bias $_0$, the driving am plitude A, and the frequency . Typical driving frequencies range up to 100 G H z [11] such that the wavelength exceeds the size of the setup and, thus, the implicitly assumed dipole approximation is well justified.

P The leads are modeled as ideal electron gases, H $_{\text{leads}} = \frac{1}{q} q (c_{Lq}^{Y} c_{Lq} + c_{Rq}^{Y} c_{Rq})$, where c_{lq}^{Y} creates an electron in lead ' = L; R. The tunneling H am iltonian

$$H_{contacts} = \bigvee_{q}^{X} V_{Lq} c_{Lq}^{y} c_{1} + V_{Rq} c_{Rq}^{y} c_{2} + H \varepsilon:$$
(2)

establishes the contact between the dot levels and the respective lead. Below, we shall assume within a sotem ed wide-band limit that the coupling strengths $\cdot = 2 \quad_{q} j y_{\cdot q} j^{2}$ ($_{q}$), $\cdot = L;R$, are energy independent. To specify the dynam ics, we choose as an initial condition for the lead electrons a grand canonical ensemble at tem – perature T and chem ical potentials $_{L;R}$. The in uence of lead \cdot is fully determ ined by the lesser G reen functions

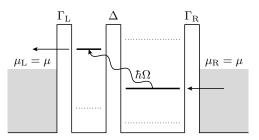


FIG.1: Level structure of the asymmetric double quantum dot in a pump conguration. The solid lines mark the relevant levels jli and j2i with the energies $_0=2$. The arrows indicate the dominating scattering process.

 $g_{'q}^{<}(t;t^{0}) = (i=h)hc_{'q}^{y}(t^{0})c_{'q}(t)i$ and the tunnelmatrix elements $V_{'q}$ [15]. More precisely, these quantities enter the expressions for the current and the noise in form of the correlation function

$$h_{1}^{y}(t) = \frac{1}{2 h^{2}} d e^{i} f_{1}(t)$$
 (3)

of the ferm ionic noise operator $\cdot = (i=h)^{r} {}_{q} V_{\cdot q} c_{\cdot q}$, where f \cdot () = (1 + exp[($\cdot)=k_{B} T$]) ¹ denotes the Ferm i function [16]. Henceforth, we consider the case of zero bias voltage with both chem ical potentials located m idway between the dot levels $_{0}=2$, i.e., $_{L} = _{R} = 0$.

Resonant electron pumping. For harm onic driving, the H am iltonian H (t) obeys tim e-reversal sym m etry and, hence, each individual scattering process has a timereversed partner which occurs with the same probability. Thus, it is tempting to conclude that the net current of both partners and, consequently, the pump current vanishes. This, how ever, is not the case because the driving enables energy non-conserving scattering. In particular, there exist processes like the one sketched in Fig.1:W ith the leads initially at equilibrium, an electron from the right lead with energy below the Ferm i surface is scattered into a state in the left lead with energy above the Ferm i surface. This process contributes to the current. By contrast, the tim e-reversed process does not transport an electron because the respective initial state is not occupied. The net e ect is transport of electrons from the low er level to the higher level, i.e., from right to left.

N one the less, the pump m ight vanish due to the presence of an additional symmetry, such as generalized parity (x;t) ! (x;t+ =) which relates two scattering processes with identical initial energies. Their contributions to the current cancel each other [16]. W ith equally strong coupling to the leads, $_{\rm L} = _{\rm R} =$, generalized parity is satised for H (t) at zero internal bias $_0 = 0$. For nite bias $_0 \notin 0$, how ever, this symmetry is broken and, consequently a nite pump current emerges. Moreover, this pump current exhibits resonance peaks including higher-order resonances [17].

W ithin our analytical approach, we focus on strongly biased situations, $_0$, and driving frequencies close to the internal resonances of the double dot, nh = $({}_0^2 + {}^2)^{1=2}$. In this regime, the dynamics of the dot electrons is dominated by the second term of the H am iltonian (1) while the tunneling contribution, which is proportional to , represents a perturbation. C onsequently, a proper interaction picture is de ned by the transform ation U (t) = exp[$\frac{i}{2}(c_1^yc_1 - c_2^yc_2)$ (t)] with the tim e-dependent phase

$$(t) = n t + \frac{A}{h} \sin(t)$$
: (4)

This yields the double-dot interaction-picture H am iltonian $\mathrm{H}^{2}_{dots}(t) = U^{y}(t)\mathrm{H}_{dots}(t)U(t)$ ih $U^{y}(t)U(t)$. The transform ation U (t) has been constructed such that $\mathrm{H}^{2}(t)$

obeys the tim e-periodicity of the original H am iltonian (1) while all its other energy scales are signi cantly smaller than h . Thus, we can separate time scales and replace $\mathrm{I\!f}_{\mathrm{dots}}(t)$ within a rotating-wave approximation (RWA) by its time average

$$H_{dots} = \frac{e}{2} (c_1^{v} c_2 + c_2^{v} c_1) - \frac{1}{2} (c_1^{v} c_1 - c_2^{v} c_2)$$
(5)

with = nh $_0$ and the electric tunnel matrix element

$$_{e} = (1)^{n} J_{n} (A = h);$$
 (6)

where J_n is the nth order B essel function of the rst kind. W hile the lead H am iltonian is una ected by the transform ation U (t), the tunneling H am iltonian acquires a tim e-dependence, $H^{0}_{contacts}(t) = \int_{q}^{W} V_{Lq} c_{Lq}^{V} c_{l} e^{i(t)=2} + V_{Rq} c_{Rq}^{V} c_{2} e^{i(t)=2}$. The lead elimination along the lines of R ef. [15], but here for a tim e-dependent contact H am iltonian, reveals that the in uence of the leads is no longer determined by the noise operators \cdot but rather by $_{L=R}(t) = e^{i(t)=2} _{L=R}(t)$. Its correlation function h $_{L=R}^{Y}(t) _{L=R}(t)$ is explicitly on the time-dimension of the leads is the reference , but also explicitly on t. The latter time-dependence is 2 = -periodic and is thereforem uch faster than all other time scales. Hence, we can replace within the RW A the correlation function of $_{L;R}$ by its t-average

$$\overline{h_{,i}^{y}(t)} = \frac{1}{2h^{2}} de^{i} f_{;e} (); (7)$$

where

$$f_{L=R,e} () = \int_{k=1}^{\frac{1}{2}} J_{k}^{2} \frac{A}{2h} f_{L=R} + \frac{h}{k} \frac{n}{2} \frac{1}{h}$$
(8)

can be interpreted as an electron occupation number of the levels in lead \cdot . At zero temperature, it exhibits steps at = $\cdot + (k \quad n=2)h$ and is constant elsewhere.

The RW A provides a mapping of the originally timedependent transport problem to a static one with renormalized parameters. This problem, in turn, can be solved by standard procedures: Both the current and the noise power can be expressed in term softhe transmission probability T () of an electron with energy . For a two-level system in the wide-band limit, one obtains

$$T() = {}^{2}jG_{12}()^{2} = \frac{2 {}^{2}}{j(2 {}^{2})^{2}} = \frac{2 {}^{2}}{\frac{2}{e}} (9)$$

Then, the current de ned as the change of the charge in the, e.g., left lead, is given by the Landauer-like formula I = (e=2 h) d T () [$\underline{f}_{;e}$ () $\underline{f}_{;e}$ ()]; the corresponding expression for the noise power reads [18]

$$S = \frac{e^{2}}{h} \begin{bmatrix} z & n & X \\ d & T & () & f_{';e} & () [1 & f_{;e} & ()] \\ & & & & \\ & & & \\ & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & &$$

Note that in the presence of a driving eld, even at zero temperature, the electron occupation $f_{\gamma_{e}}$ is not a simple step function and, thus, also the term in the rst line of Eq. (10) contributes to the noise power. A convenient measure for the relative noise strength is the Fano factor F = S=2eI which characterizes the noise with respect to the shot noise level given by S = 2eI [18].

For the remaining evaluation of the energy integrals, it is important to note that the transmission (9) is practically zero for $2 > \frac{2}{e} + 2 + 2$. Thus, for h $> \frac{2}{e}$; ; the electron occupation (8) is constant in the relevant energy range and can be replaced by its value at = 0.0 ne obtains close to the nth resonance

$$I^{(n)} = \frac{e}{2h} \frac{n}{\frac{2}{e} + 2 + 2};$$
(11)

$$S^{(n)} = \frac{e^{2}}{2h} \frac{\begin{pmatrix} 2 & 2 \\ n & e \end{pmatrix}}{(2h)^{2}} \frac{\left(2 + 2 \right)^{2}}{(2h)^{2}} \frac{\left(2 & 3^{2} \right) + \left(4 \\ e & e \end{pmatrix}}{(2h)^{2}} \frac{\left(2 + 2 + 2 \right)^{3}}{(2h)^{2}} + \frac{1}{2h} \frac{\left(2 + 2 \right)^{2}}{(2h)^{2}} \frac{\left(2 + 2 + 2 \right)^{3}}{(2h)^{2}}$$
(12)

where $_{n} = f_{L;e}(0) \quad f_{R;e}(0) = \int_{kj n=2}^{P} J_{k}^{2} (A=2h)$ with $j_{n}j$ 1. Quite remarkably, for resonant driving (= 0), the pump current assumes a maximum while the noise power S generally assumes a local minimum; cf. Fig. 2(a). This results in an even more pronounced minimum for the Fano factor.

F loquet transport theory. Before developing an optim ization strategy, we corroborate our analytical results by an exact num erical calculation within F loquet transport theory [16]: Starting from the Heisenberg equations of motion for the annihilation operators for both the lead and the dot electrons, one elim inates the lead operators and thereby obtains for the electrons on the dots a reduced set of equations. These are solved with the help of the retarded G reen function obeying $H(t) + i = 2]G(t;t^0) =$ [ihd=dt (t t); where H (t) is the single-particle Ham iltonian corresponding to the double-dot H am iltonian (1). The coe cients of the equation of m otion for G $(t;t^0)$ are 2 = -periodic and, consequently, its solution can be constructed with the help of the Floquet ansatz j (t)i = exp[(i =h)t]j (t)i. The Floquet states j (t) i obey the eigenvalue equation ihd=dt]j (t)i= (ih)j (t)i. Its [H (t) i =2 solution allows to construct the retarded G reen function G $(t;t^0) =$ (i=h) j (t)ih ⁺ (t⁰)j (t t⁰). Finally, one obtains for the pump current a convenient Landauer-like expression with an additional sum over the sidebands [16, 19]. Since the symmetrized noise correlation function $S(t;t^0) = h[I(t);I(t^0)]_+ i$ depends explicitly on both times, we characterize the noise by the time-average of its zero-frequency component, $S = (2 =) \begin{bmatrix} R_2 \\ 0 \end{bmatrix} = \begin{bmatrix} R \\ 0 \end{bmatrix} dt d S (t; t)$. $(2 =) \frac{1}{0}$

Figure 2 (a) depicts the num erically evaluated pump current and its noise power. For proper cooling, therm al excitations do not play a signi cant role. Therefore, we

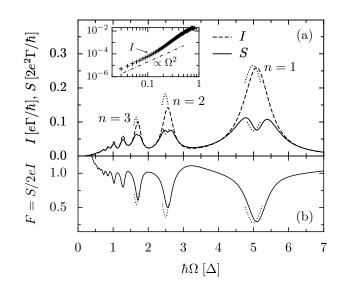


FIG.2: (a) Pump current I (dashed line) and its noise power S (solid) at $k_{\rm B}$ T = 0 as a function of the driving frequency for coupling strength = 0:3 , driving am plitude A = 3:7 , and internal bias $_0$ = 5 . The dotted lines mark the analytical results (11) and (12). Inset: B low -up of the low er-left corner dem onstrating that I / 2 . (b) Corresponding Fano factor.

consider zero tem perature only. We nd that the current exhibits peaks located at the resonance frequencies = $(\binom{2}{0} + \binom{2}{1})^{1=2}$ = nh. This agrees well with our analytical results (dotted lines), albeit the RW A predicts the location of the current maxim a only to zeroth order in , i.e., at the slightly shifted frequencies = $_0$ =nh. In the adiabatic lim it, the pump current vanishes proportional to 2 . For the chosen parameters, the noise power S possesses clearm in in a, each accompanied by two maxima. In the vicinity of the resonance, the noise is considerably below the shot noise level 2eI; cf. Fig. 2(b). This feature is notably pronounced at the rst resonance. Far from the resonances, the current becomes smaller and the Fano factor is close to F = 1. The comparison of the num erically exact results with the current (11) and the noise power (12) [dotted lines in Fig. 2(a)] leads to the conclusion, that the RW A predicts both the current maxim a and the noise minim a su ciently well to employ these expressions for a parameter optimization towards low-noise pum ping.

Tuning the electron pump. | W e have already seen that the condition of large current and low noise is met at the internal resonances of the biased double-dot setup. Thus, we can restrict the search for optim al parameters to resonant driving. As a gure of merit for the noise strength we employ the Fano factor for = 0

$$\mathbf{F}^{(n)} = \frac{\mathbf{S}^{(n)}}{2\mathbf{e}\mathbf{I}^{(n)}} = \frac{1}{2_{n}} - \frac{n}{2} \frac{\frac{2(3 \frac{2}{e} - 2)}{(\frac{2}{e} + 2)^{2}}}; \quad (13)$$

which is a function of p^{p} and e^{e} = . The second term is minimal for $e^{e} = \frac{1}{5-3}$, yielding F⁽ⁿ⁾ = 1=(2 n)

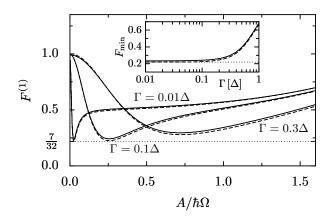


FIG. 3: Fano factor F at the rst resonance for various coupling strengths . The exact F loquet calculation (solid lines) is compared with the RWA for = 0 (dashed). The inset depicts the minimal Fano factor in dependence of for $_0 = 5$ at the resonance = $\frac{1}{2} + \frac{2}{0} = h$. The dotted lines mark the optimal Fano factor $F_{opt} = 7=32$.

9 $_{n}$ =32. Thus, the optimal Fano factor is assumed for $_{n}$ = 1 and reads F_{opt} = 7=32 0.219.

In the following, we restrict ourselves to the prime resonance (n = 1) for which $_{e} = J_{1}$ (A = h) and $_{1} = J_{0}^{2}$ (A = 2h) [20]. Then, the value $_{1} = 1$ is assum ed for A = 0 which means e = 0; this unfortunately implies a vanishing current (11). Therefore, the central question is whether it is possible to nd a driving am plitude providing on the one hand an appreciably large pump current, while on the other hand yielding a noise level close to Fopt. The num erical results depicted in Fig. 3 indeed suggest this possibility: The Fano factor is close to the optim al value already for a nite am plitude. A closer investigation reveals that the location of them inin un corresponds to $_{e} = J_{1} (A = h) =$ 5=3 , in com pliance with our analytical considerations. In particular, the minimum is shifted towards smaller values of A=h for weaker coupling . M oreover, the RW A solutions (11) and (12) agree very well with the num erically exact results, although they slightly underestim ate the noise. This discrepancy dim inishes as 2 (not shown).

The data also reveal that in the interesting regime, the ratio A=h is considerably sm aller than 1 and, hence, we can employ the approximations $J_0(x) = 1$ x≠=4 and J₁ (x) x=2 valid for sm allargum ents. It is now straightforward to obtain to low est order in A = h the expressions $_{e}$ = A = 2h and F ⁽¹⁾ = 7=32 + (5A=16h)². For instance, choosing A = 0.3h, the noise level lies merely 5% above F_{opt} and the condition e = 15=3 corresponds to 0:1, i.e., to weak dot-lead coupling. This estimate is con med by the inset in Fig. 3 which, in addi- F_{opt} for < 0:1 . For such tion, dem onstrates that F a sm all coupling , interaction-induced electron-electron correlations typically play a m inor role.

In the experim ent of R ef. [11], a typical inter-dot cou-

pling is = 50 eV. Then, an internal bias $_0 = 5$ corresponds to the resonance frequency = 5 =h 2 60G Hz. Tuning the lead coupling to = 0:1 results in an optimized pump current of the order 200pA with a Fano factor F 0:23.

Conclusions. The analysis of ac-driven, asymmetric double quantum dots dem onstrates that optim al pum ping is achieved beyond the adiabatic regime. In particular, the ideal modus operandi requires a large internal bias at resonant driving in combination with a strong inter-dot coupling > 10 . The resulting pum p current then assumes a maximum while, interestingly enough, the (absolute) noise power assumes at the same time a m in im um such that the Fano factor becom es rem arkably small. In order to system atically tune the pump into a low -noise regime, we have derived analytical expressions for both the current and its noise power. The com parison with the num erically exact solution fully con rms the validity of this approach. Our ndings convincingly suggest that coupled quantum dots are ideal for pum ping electrons e ectively and reliably at a low noise level.

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